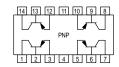
Quad General Purpose Transistors

PNP Silicon

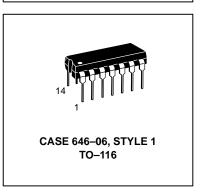


MPQ2906 MPQ2907 MPQ2907A*

*Motorola Preferred Device

MAXIMUM RATINGS

Rating	Symbol	MPQ2906 MPQ2907	MPQ2907A	Unit
Collector-Emitter Voltage	VCEO	-40	-60	Vdc
Collector-Base Voltage	Vсво	-60		Vdc
Emitter-Base Voltage	VEBO	-5.0		Vdc
Collector Current — Continuous	IC	-6	mAdc	
		Each Transistor	Total Device	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	0.65 6.5	1.9 19	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +125		°C



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	66	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS		•			
Collector-Emitter Breakdown Voltage ⁽¹⁾ (I _C = -10 mAdc, I _B = 0)	MPQ2906, MPQ2907 MPQ2907A	V(BR)CEO	-40 -60	_ _	Vdc
Collector-Base Breakdown Voltage (I _C = -10 μAdc, I _E = 0)		V(BR)CBO	-60	_	Vdc
Emitter-Base Breakdown Voltage ($I_E = -10 \mu Adc, I_C = 0$)		V(BR)EBO	-5.0	_	Vdc
Collector Cutoff Current (V _{CB} = -30 Vdc, I _E = 0) (V _{CB} = -50 Vdc, I _E = 0)	MPQ2906, MPQ2907 MPQ2907A	ICBO	_	-50	nAdc
Emitter Cutoff Current (VEB = -3.0 Vdc, IE = 0)	MPQ2906,7 Only	I _{EBO}	_	-50	nAdc

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

Preferred devices are Motorola recommended choices for future use and best overall value.

REV 3



MPQ2906 MPQ2907 MPQ2907A

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit
ON CHARACTERISTICS			•		
DC Current Gain(1) (IC = -100 μAdc, VCE = -10 Vdc) (IC = -1.0 mAdc, VCE = -10 Vdc) (IC = -10 mAdc, VCE = -10 Vdc) (IC = -10 mAdc, VCE = -10 Vdc) (IC = -150 mAdc, VCE = -10 Vdc) (IC = -150 mAdc, VCE = -10 Vdc) (IC = -300 mAdc, VCE = -10 Vdc)	MPQ2907A MPQ2907A MPQ2906 MPQ2907 MPQ2907A MPQ2907A MPQ2906 MPQ2907	hFE	75 100 35 75 100 100 40 100 20	 300 	_
$(I_{C} = -500 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$	MPQ2907 MPQ2907A		30 50	_	
Collector-Emitter Saturation Voltage ⁽¹⁾ $(I_C = -150 \text{ mAdc}, I_B = -15 \text{ mAdc})$ $(I_C = -300 \text{ mAdc}, I_B = -30 \text{ mAdc})$ $(I_C = -500 \text{ mA}, I_B = -500 \text{ mA})$	MPQ2906, MPQ2907 MPQ2907A	VCE(sat)	_ _ _	-0.4 -1.6 -1.6	Vdc
Base-Emitter Saturation Voltage ⁽¹⁾ $(I_{C} = -150 \text{ mAdc}, I_{B} = -15 \text{ mAdc})$ $(I_{C} = -300 \text{ mAdc}, I_{B} = -30 \text{ mAdc})$ $(I_{C} = -500 \text{ mA}, I_{B} = -50 \text{ mA})$	MPQ2906, MPQ2907 MPQ2906, MPQ2907 MPQ2907A	VBE(sat)	_ _ _	-1.3 -2.6 -2.6	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain — Bandwidth Product (I _C = -50 mAdc, V _{CE} = -20 Vdc, f = 100 MHz)		fT	200	_	MHz
Output Capacitance ($V_{CB} = -10 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$	2)	C _{obo}	_	8.0	pF
Input Capacitance (V _{EB} = 2.0 Vdc, I _C = 0, f = 1.0 MHz)		C _{ibo}	_	30	pF
SWITCHING CHARACTERISTICS					
Turn–On Time $(V_{CC} = -30 \text{ Vdc}, I_C = -150 \text{ mAdc}, I_{B1} = 15 \text{ mAdc})$	MPQ2907A Only	ton	_	45	ns
Turn–Off Time $(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -150 \text{ mAdc}, I_{B1} = I_{B2} = 15 \text{ mAdc})$	MPQ2907A Only	t _{off}	_	180	ns

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

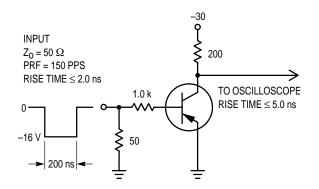


Figure 1. Delay and Rise Time Test Circuit

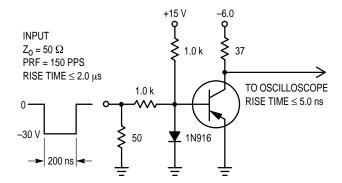


Figure 2. Storage and Fall Time Test Circuit

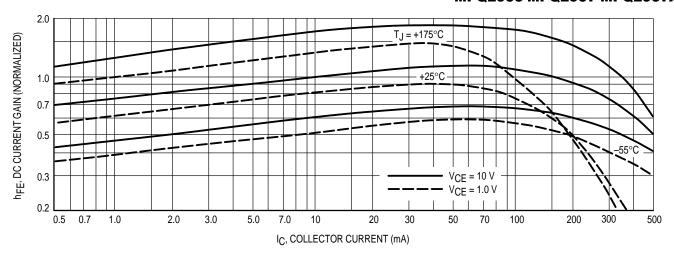


Figure 3. DC Current Gain

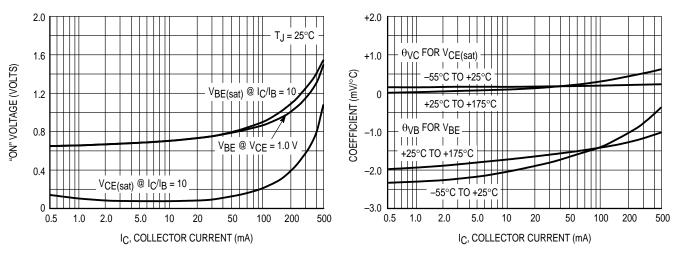


Figure 4. "ON" Voltages

Figure 5. Temperature Coefficients



 $(VCE = 10 \text{ V}, TA = 25^{\circ}C)$

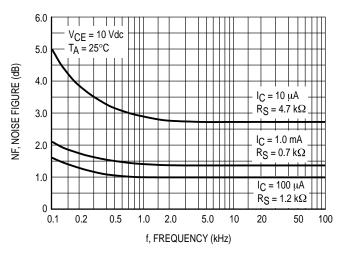


Figure 6. Frequency Effects

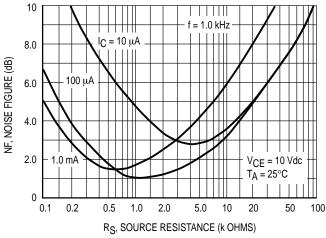


Figure 7. Source Resistance Effects

MPQ2906 MPQ2907 MPQ2907A

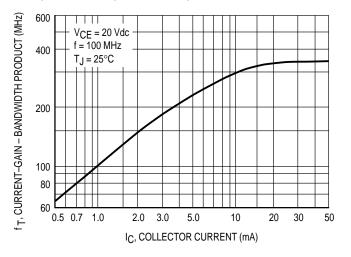


Figure 8. Current-Gain — Bandwidth Product

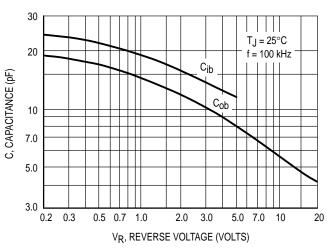


Figure 9. Capacitance

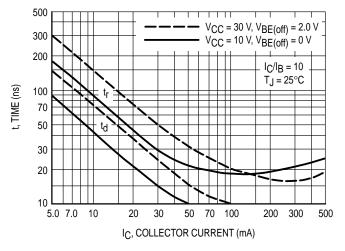


Figure 10. Turn-On Time

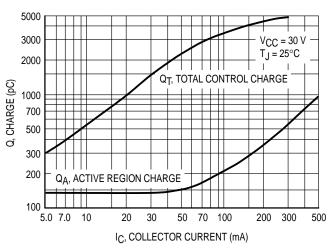


Figure 11. Charge Data

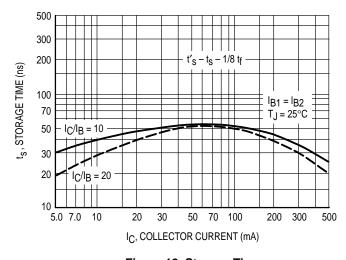


Figure 12. Storage Time

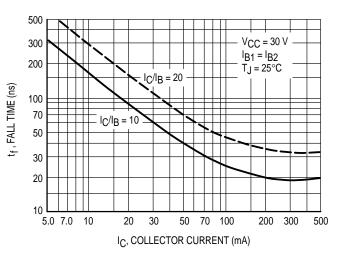
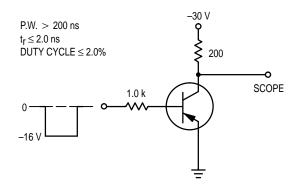


Figure 13. Fall Time



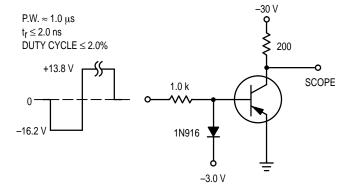
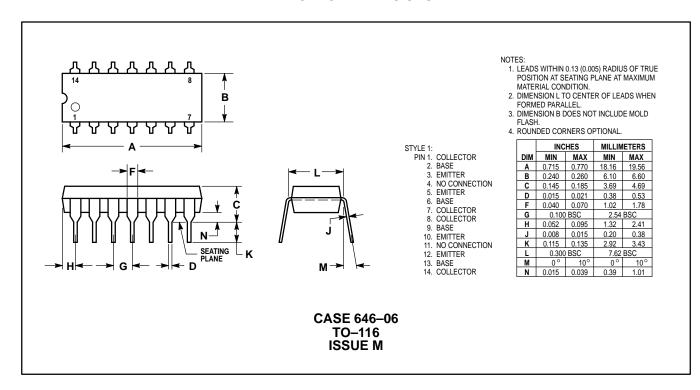


Figure 14. Delay and Rise Time Test Circuit

Figure 15. Storage and Fall Time Test Circuit

PACKAGE DIMENSIONS



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Mfax™: RMFAX0@email.sps.mot.com - TOUCHTONE 602-244-6609 INTERNET: http://motorola.com/sps

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ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, US & Canada ONLY 1-800-774-1848 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298



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